

Signal and power integrity fundamentals

Theory and
demos



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A **practical and useful seminar** discovering the fundamentals of Signal and Power Integrity for electronic circuits.

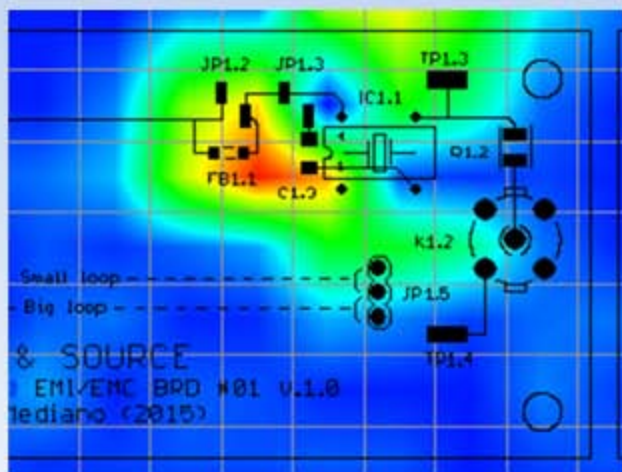
Organized by



ROHDE & SCHWARZ



A High Frequency Lab for design, diagnostic, troubleshooting and training



Interferences (**EMI**)
Electromagnetic Compatibility (**EMC**)
Signal Integrity (**SI**)
Radiofrequency (**RF**)

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Outline: for this session.

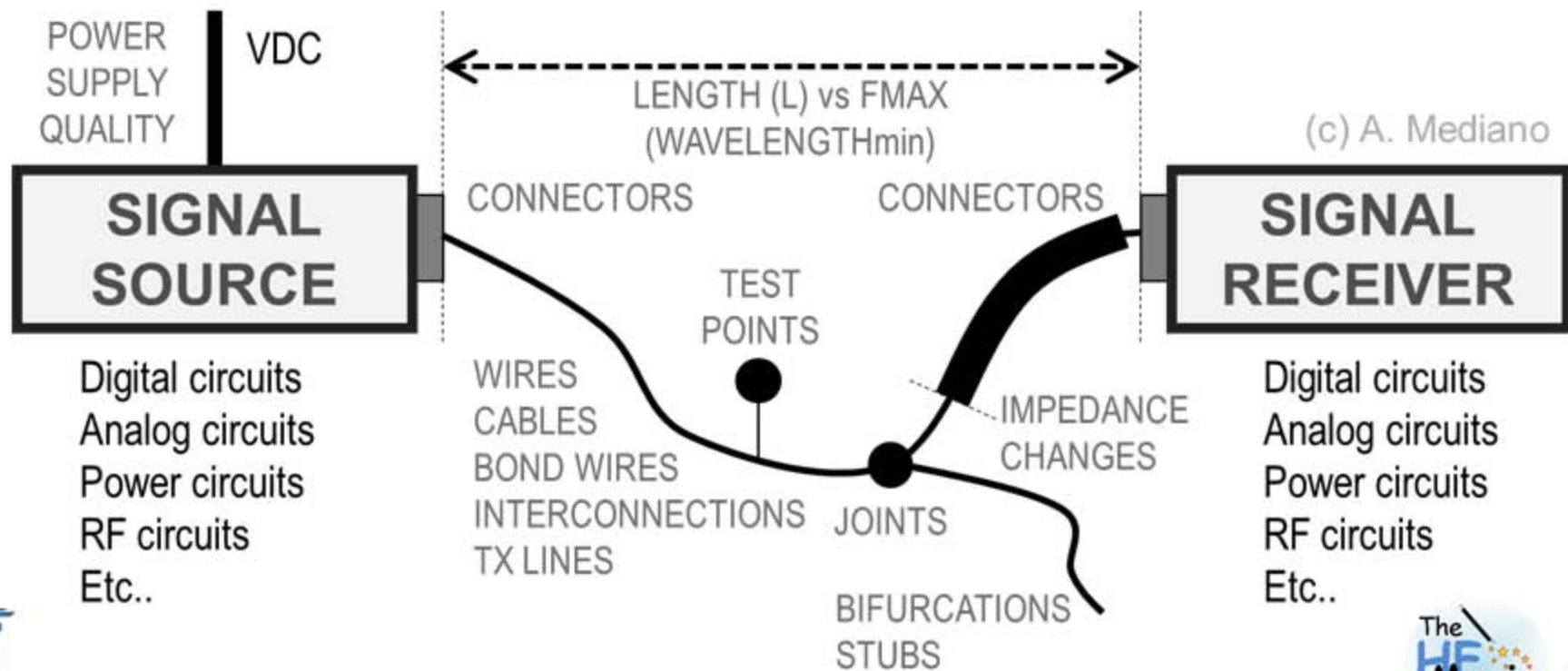
- **Signals and bandwidth**
- **Return path**
- **TX lines**
- **S-parameters**
- **Smith chart**
- **Eye diagram and jitter**
- **Matching**
- **Power integrity: decoupling**
- **Instrumentation**



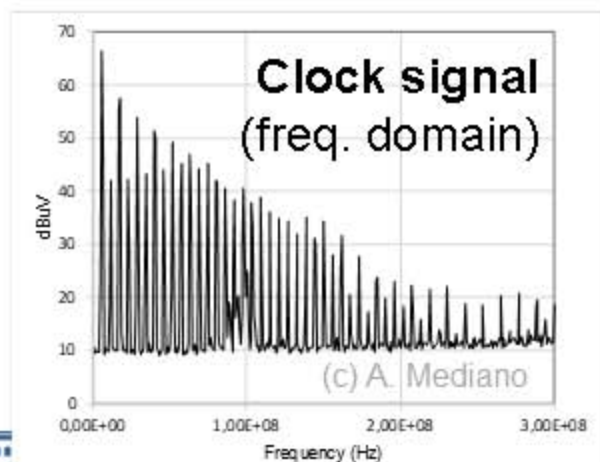
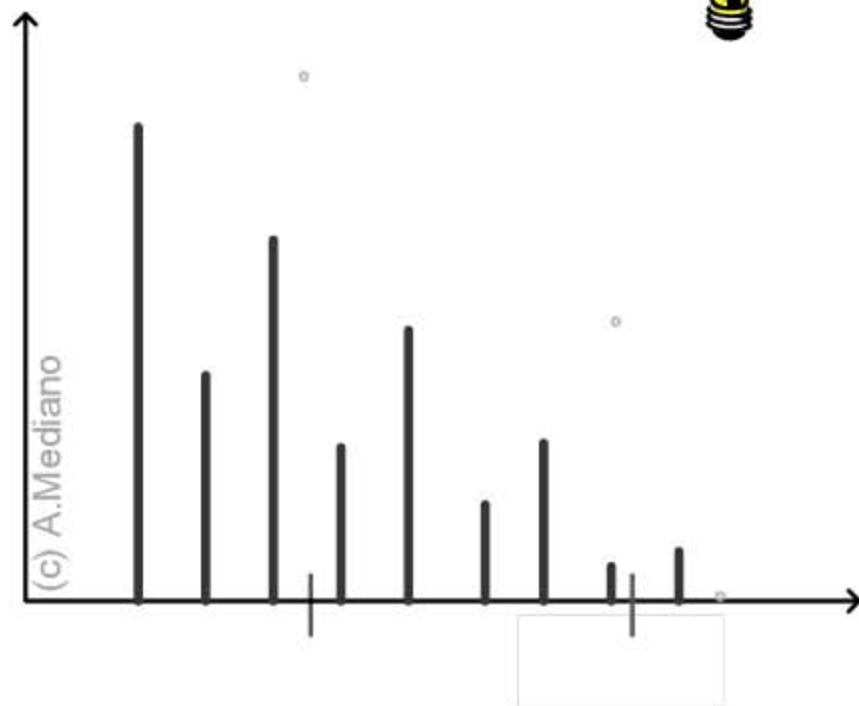
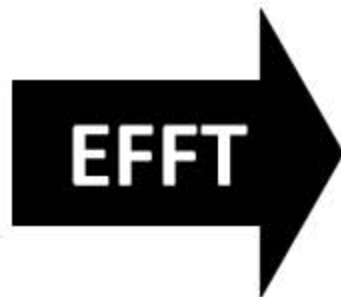
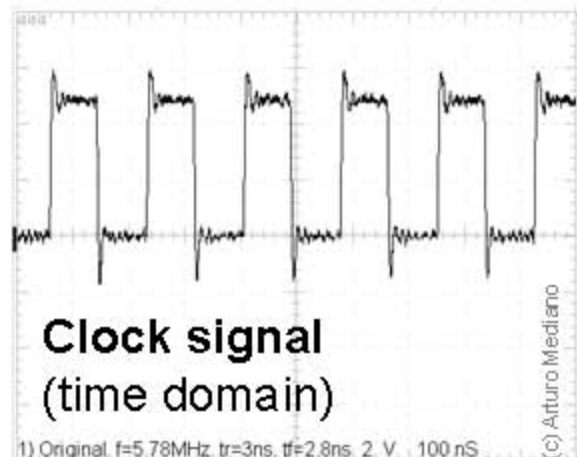
Introduction: SI/PI general picture

SI IS RELATED WITH THE EFFECT OF INTERCONNECTIONS QUALITY BETWEEN A SIGNAL SOURCE AND ITS RECEIVER CIRCUITS

REFLECTIONS · CROSSTALK · RAIL COLLAPSE (PI)



Spectrum: the EFFT and bandwidth



Example:

1ns → 300MHz

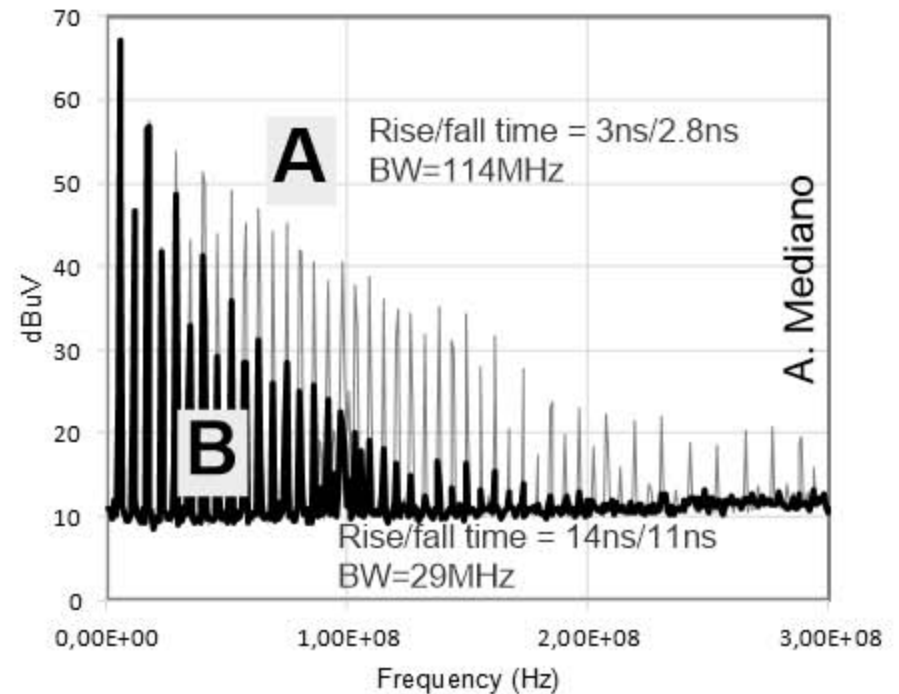
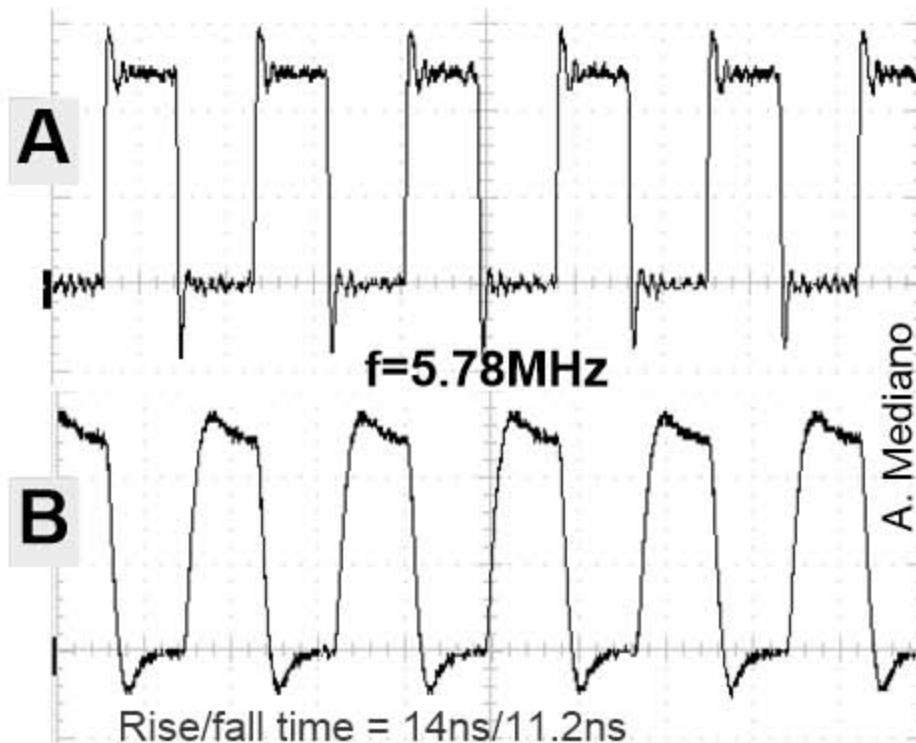
Same thing for non periodic signals (e.g. ESD).

$$\frac{dv}{dt} \uparrow\uparrow \quad \frac{di}{dt} \uparrow\uparrow$$

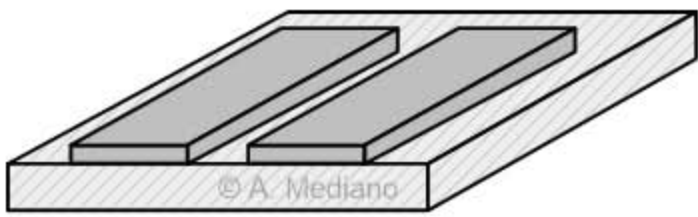
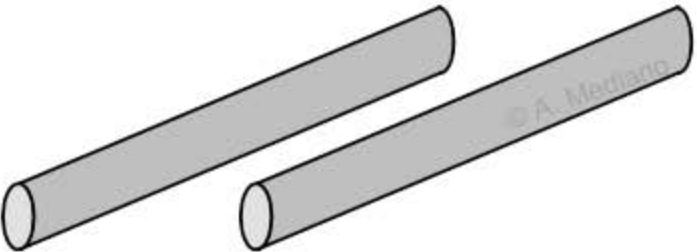
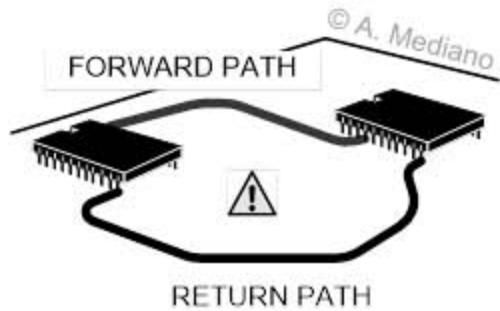
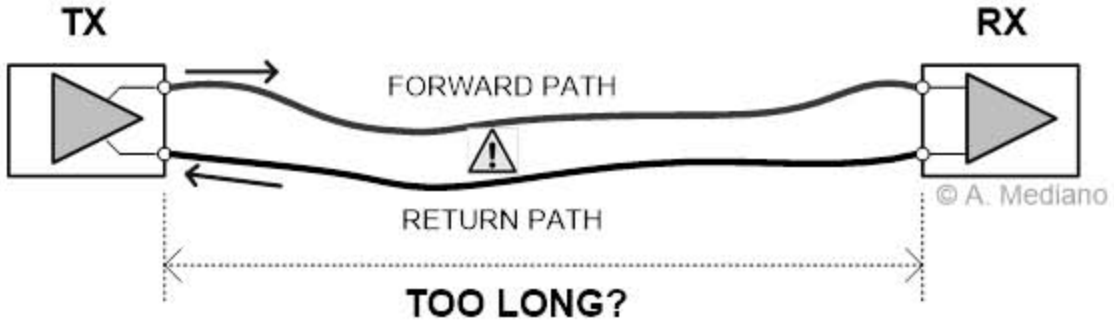
= DANGER!!!



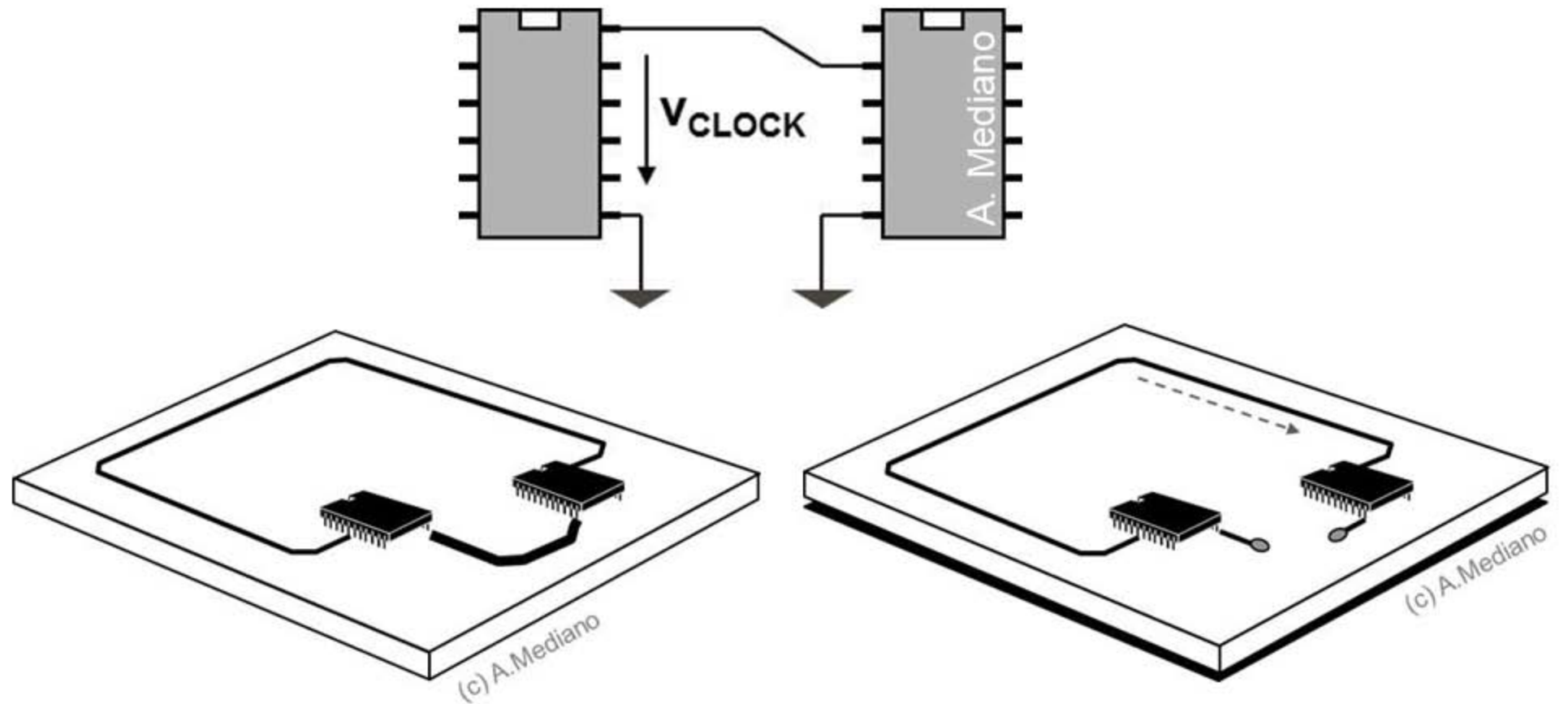
Spectrum: the EFFT and bandwidth



SI: layout of high BW signals



SI: ground layout



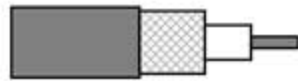
TX lines: basic behavior

SOME EXAMPLES:

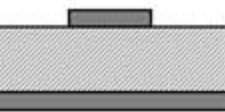
PARALLEL OR
TWISTED
CONDUCTORS



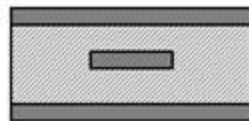
COAXIAL



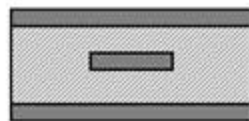
(c) A. Mediano



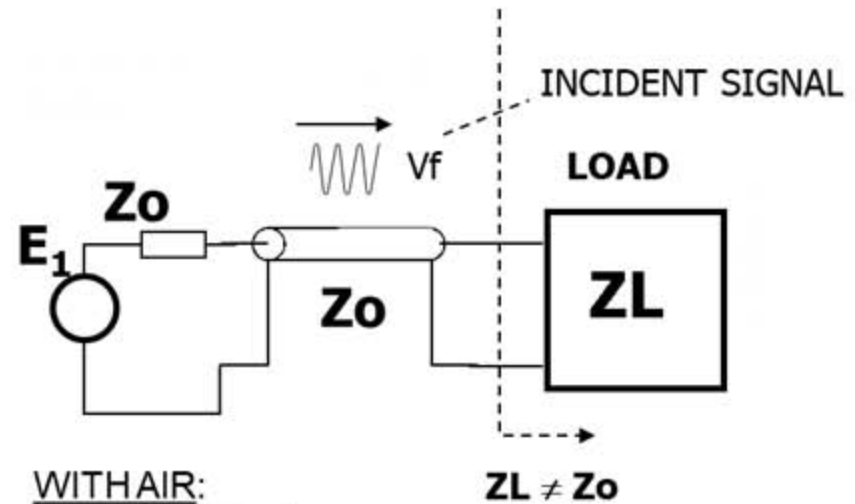
MICROSTRIP



STRIPLINE



COPLANAR



WITH AIR:

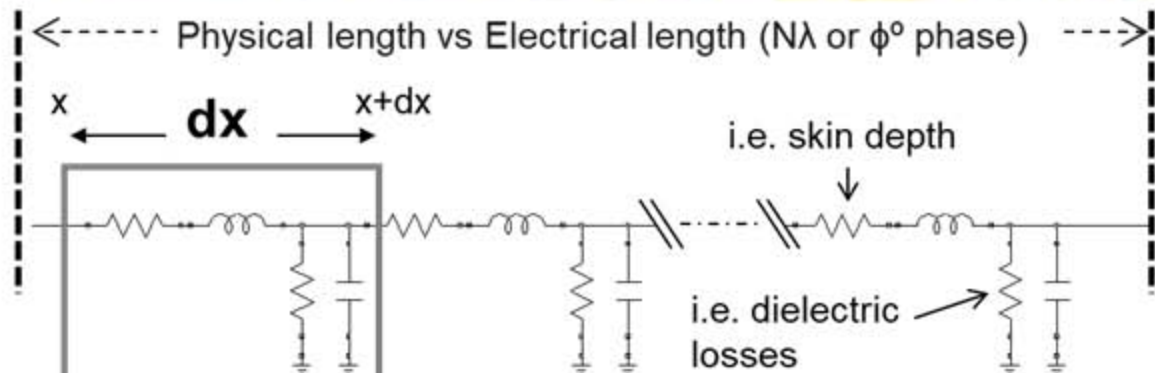
$c = 300.000 \text{ km/s}$

WITH DIELECTRIC:

The dielectric slows the signal: $v_s := \frac{c}{\sqrt{\epsilon_{\text{eff}}}}$



TX lines: circuital model

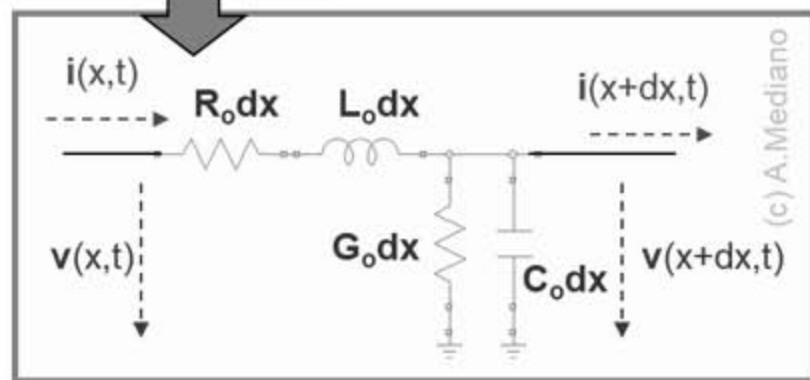


Propagation velocity:

$$v_p(\epsilon_{r_eff}) := \frac{c_0}{\sqrt{\epsilon_{r_eff}}} := \frac{1}{\sqrt{L_0 \cdot C_0}}$$

Propagation delay

$$\tau_{pd} := \sqrt{L_0 \cdot C_0} \quad \text{ps/mm}$$



Characteristic impedance

$$Z_0 := \sqrt{\frac{R_0 + j \cdot \omega \cdot L_0}{G_0 + j \cdot \omega \cdot C_0}} \approx \sqrt{\frac{L_0}{C_0}} \quad \Omega$$

$$L_0 := Z_0 \cdot \tau_{pd}$$

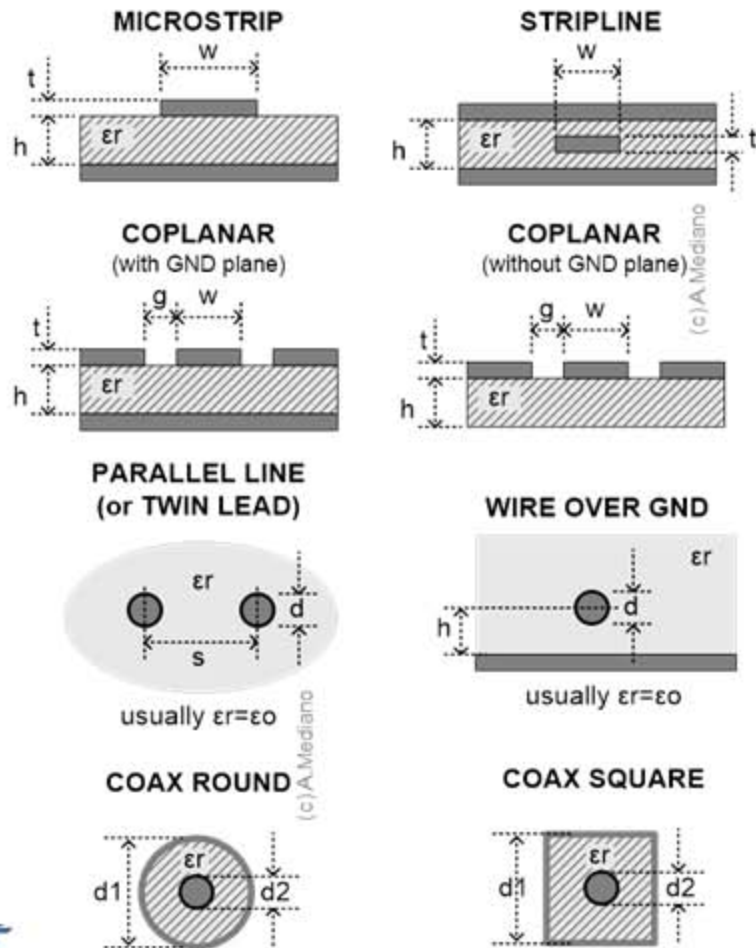
$$C_0 := \frac{\tau_{pd}}{Z_0}$$

Loss in TX lines = **Attenuation + Risetime degradation** [because loss(f)]

$$V(x,t) := V\left(t - \frac{x}{v}\right) + V\left(t + \frac{x}{v}\right) \quad I(x,t) := \left(\frac{V_i}{Z_0}\right) - \left(\frac{V_r}{Z_0}\right)$$

Incident V_i
 Reflected V_r

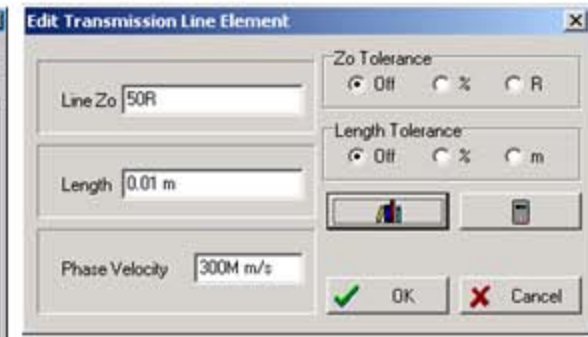
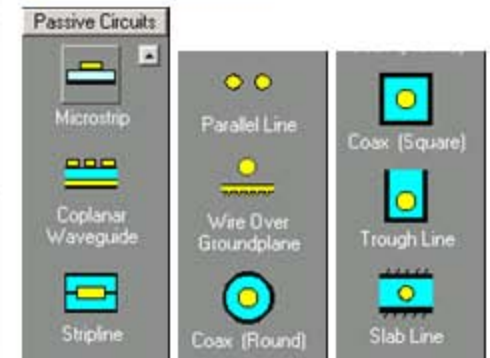
TX lines: analysis/synthesis



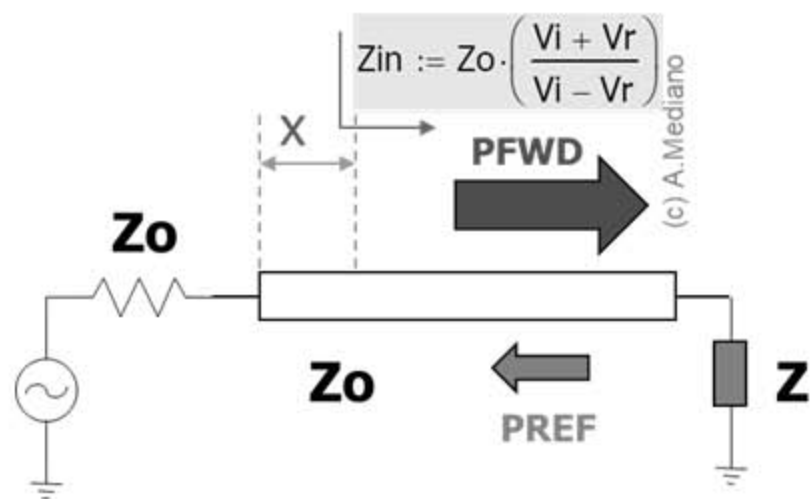
RFSIM



AppCAD



TX lines: specifying matching



STANDING WAVE RATIO ...

$$|V_{max}| = |V_i| + |V_r| = |V_i| (1 + |\Gamma|)$$

$$|V_{min}| = |V_i| - |V_r| = |V_i| (1 - |\Gamma|)$$

$$20\text{LOG}(V_{max}/V_{min}) = 20\text{LOG}[(1 + |\Gamma|)/(1 - |\Gamma|)]$$

$$\text{VSWR} := \frac{1 + |\Gamma|}{1 - |\Gamma|} \quad 0 \leq |\Gamma| \leq 1 \rightarrow \text{VSWR} \geq 1$$

Ej.: **1.4:1**

(c) A. Mediano

REFLECTION COEFFICIENT ...

$$\Gamma := \frac{V_r}{V_i} \rightarrow \Gamma := \frac{Z - Z_o}{Z + Z_o}$$

$\Gamma = -1$ (full negative reflection, short circuit)

$\Gamma = 0$ (no reflection, perfect match)

$\Gamma = 1$ (full positive reflection, open circuit)

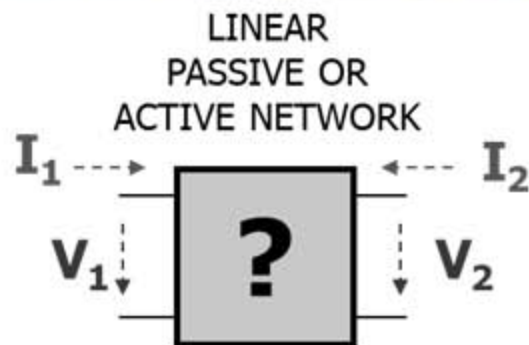
INPUT REFLECTION COEFFICIENT RC ...

s_{11} = Input reflection coef. = V_{ref}/V_{fwd}

$s_{11_{dB}} = 20 \text{ LOG } s_{11} \rightarrow$ Negative number

$$P_{ref} = \Gamma^2 \times P_{fwd}$$

S parameters: introduction.



IMPEDANCES $V_1 := z_{11} \cdot I_1 + z_{12} \cdot I_2$

[Z] $V_2 := z_{21} \cdot I_1 + z_{22} \cdot I_2$

ADMITANCES $I_1 := y_{11} \cdot V_1 + y_{12} \cdot V_2$

[Y] $I_2 := y_{21} \cdot V_1 + y_{22} \cdot V_2$

HYBRID $V_1 := h_{11} \cdot I_1 + h_{12} \cdot V_2$

[H] $I_2 := h_{21} \cdot I_1 + h_{22} \cdot V_2$

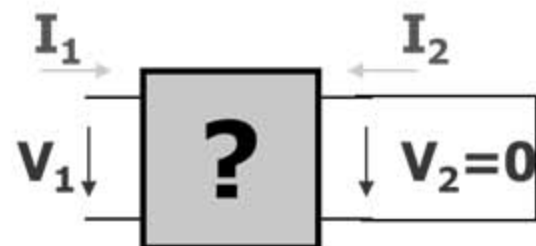
DEPENDENT VARIABLES
(RESPONSE)

INDEPENDENT VARIABLES
(EXCITATION)

EXTRACTION OF Z, H & Y parameters

Example:

$$h_{11} := \frac{V_1}{I_1} \Big|_{V_2=0}$$



High frequency limitations

a) Limitations for instruments to measure V and I.

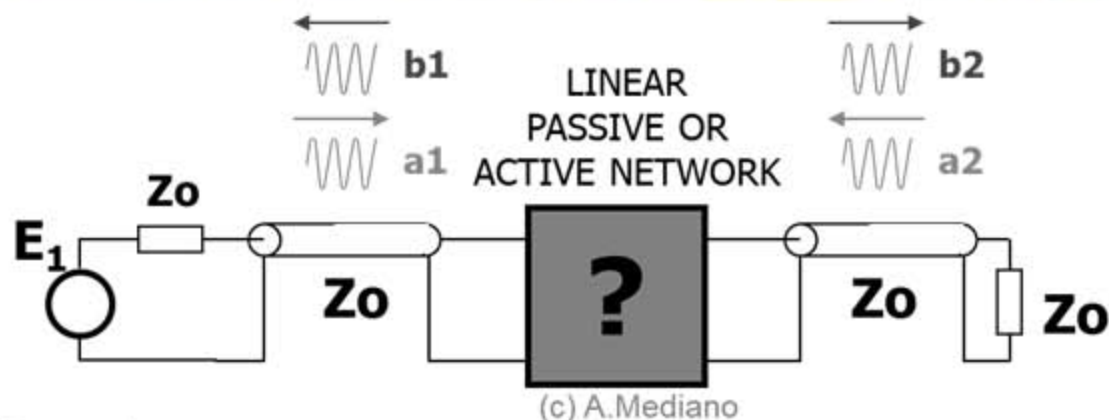
b) Shorts and Opens difficult to implement.

c) Some active networks can oscillate with shorts or opens in their ports.



S parameters: definition.

Scattering parameters



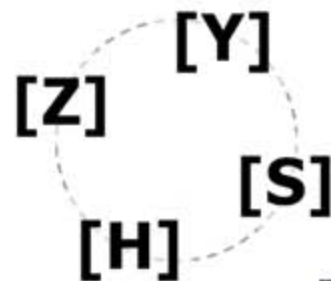
$$[b] = [S] \times [a]$$

$$b_1 := S_{11} \cdot a_1 + S_{12} \cdot a_2$$

$$b_2 := S_{21} \cdot a_1 + S_{22} \cdot a_2$$

IMPORTANT IDEAS

- The system is defined with s_{11} , s_{12} , s_{21} , s_{22} and Z_0 .
- S parameters are complex numbers
- It is easy to convert parameters:



S parameters: Touchstone format

! Comments

Title

Test conditions

Data format

! 2N5179A.S2P

! VCE=6V; IC=1.5mA

GHZ S MA R 50

! S-PARAMETERDATA

f	S ₁₁	S ₂₁	S ₁₂	S ₂₂
0.1	0.86 -25	3.59 145	0.03 74	0.95 -10
0.2	0.68 -44	3.02 122	0.06 66	0.88 -15
0.35	0.49 -61	2.21 100	0.08 62	0.82 -22
0.5	0.4 -72	1.71 86	0.1 61	0.8 -28
0.65	0.33 -80	1.37 75	0.12 61	0.79 -33
0.8	0.27 -88	1.15 66	0.13 61	0.78 -39
1	0.2 -105	0.95 56	0.14 62	0.76 -47
1.25	0.14 -130	0.79 46	0.16 64	0.75 -57
1.5	0.09 -177	0.67 37	0.19 69	0.75 -66

GHZ S MA R 50

MHZ
GHZS
Y
ZMA
DBRef.
Zo

© A. Mediano

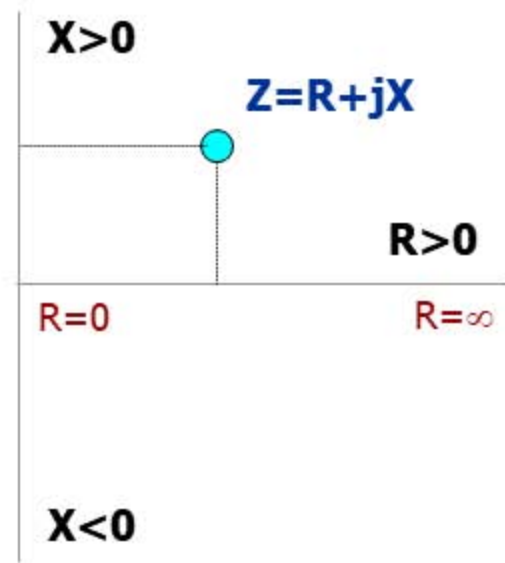
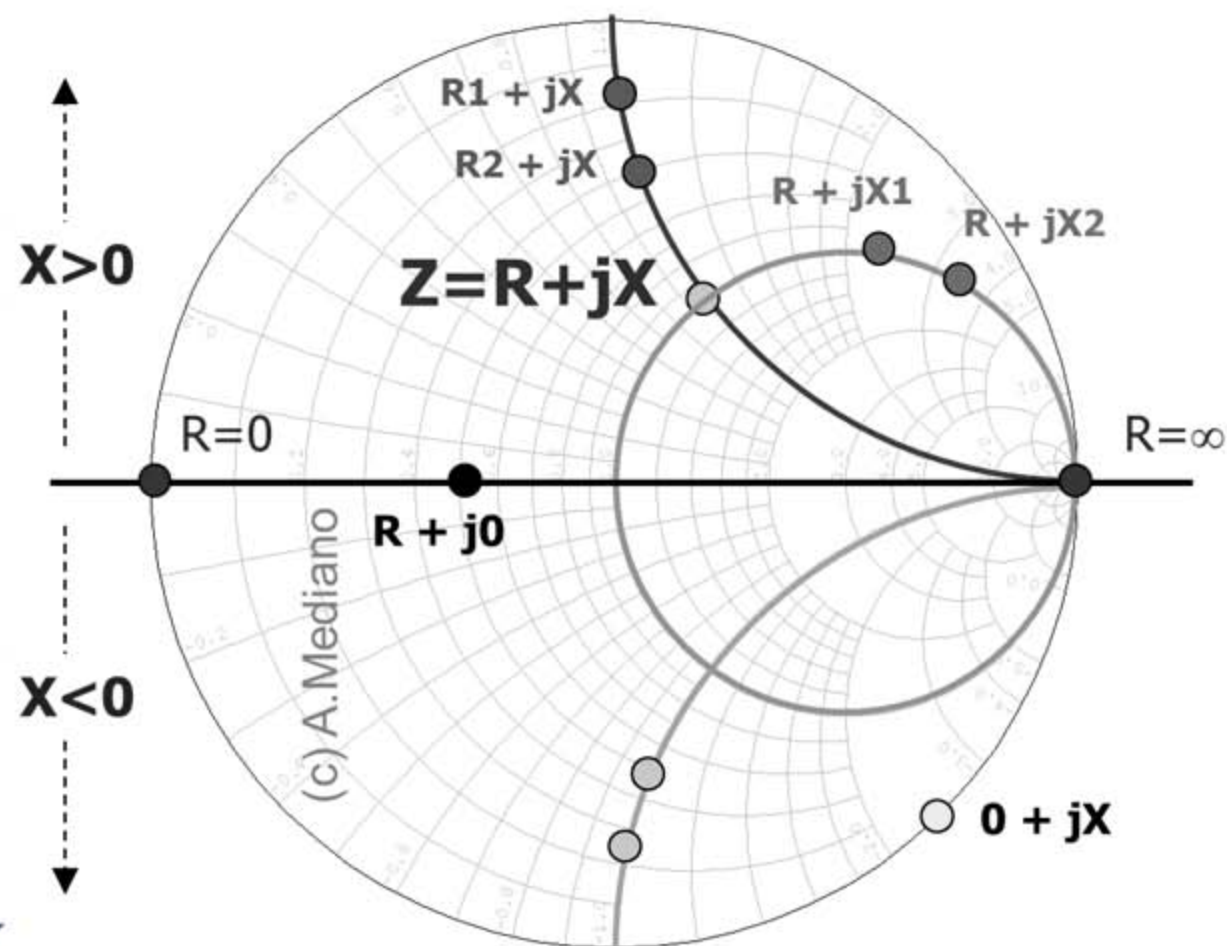
f

S₁₁S₂₁S₁₂S₂₂

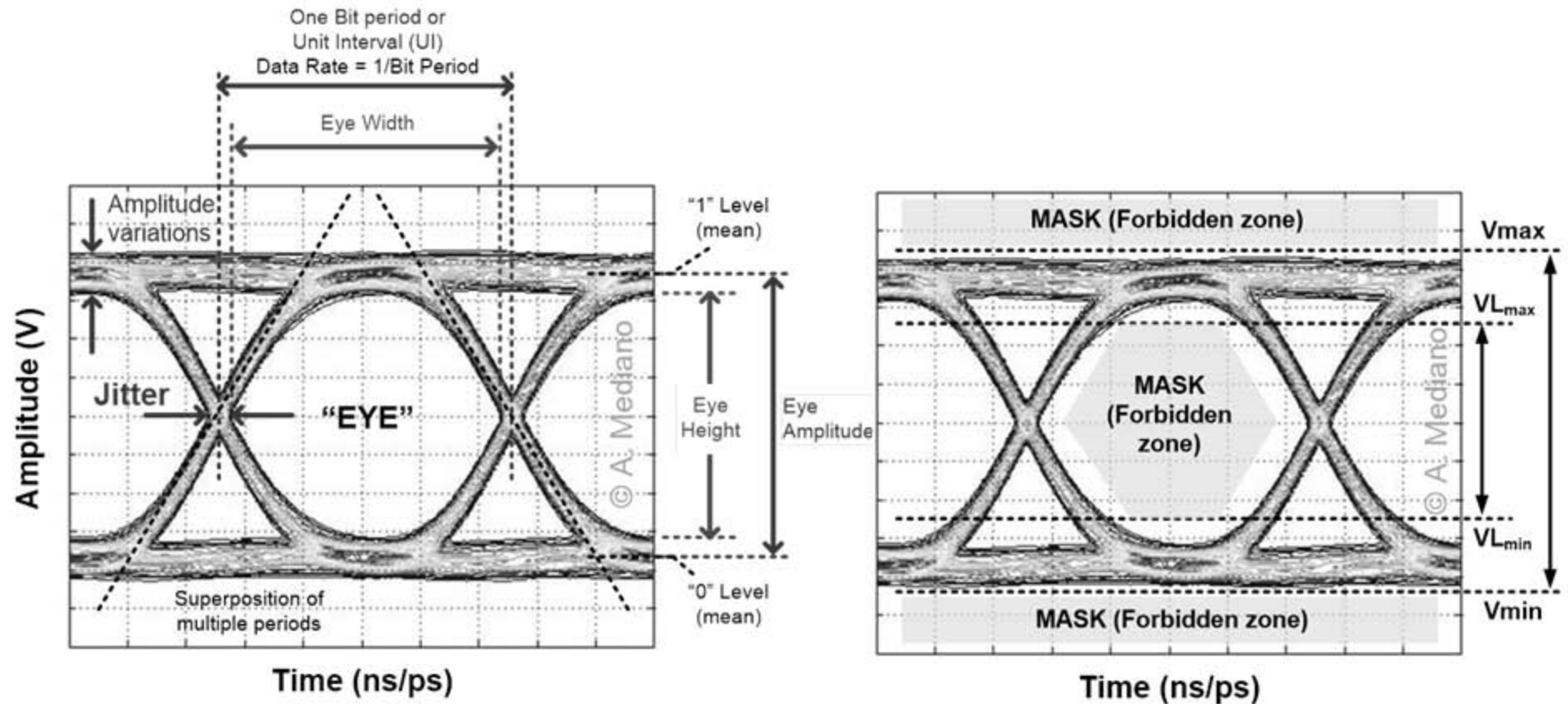
*.s2p FILES



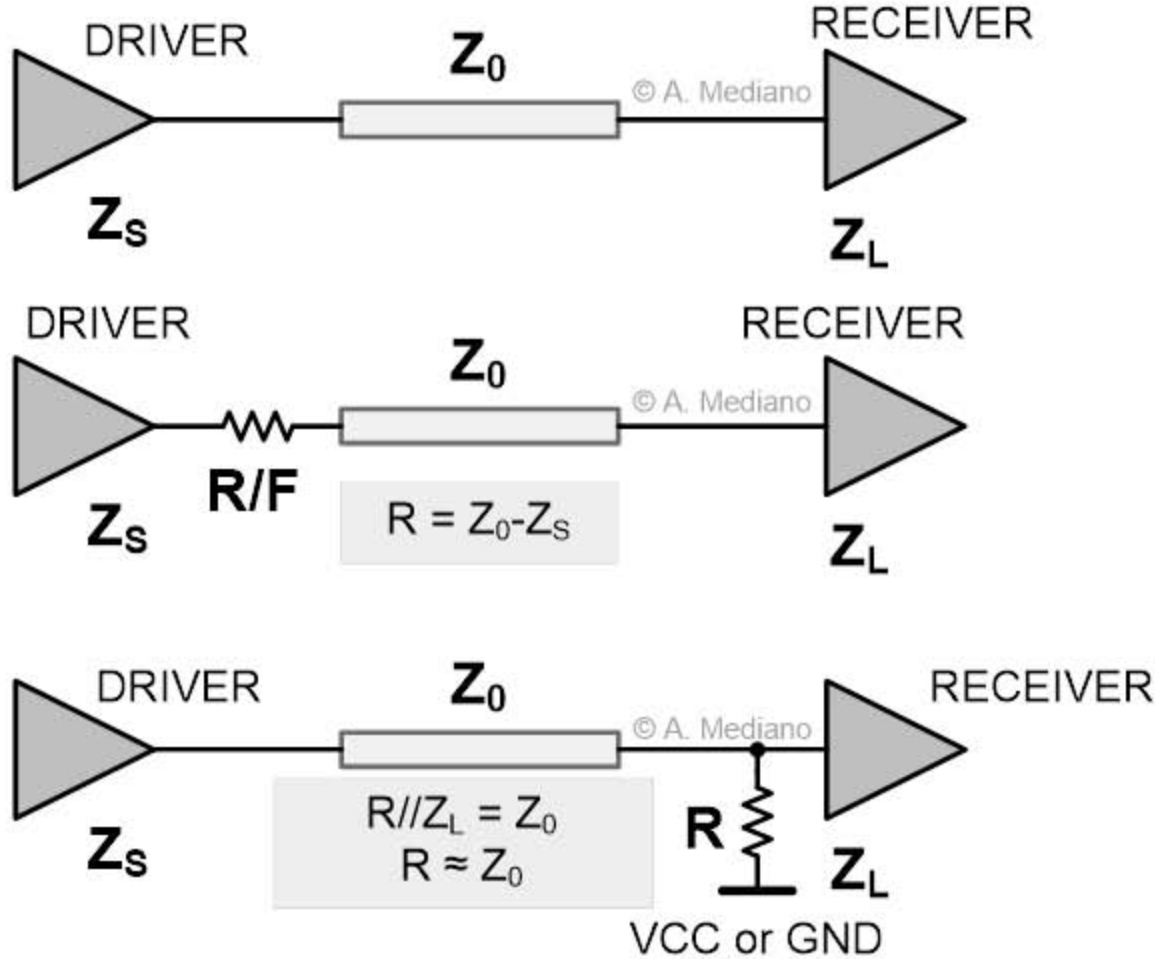
Smith chart: graphical tool.



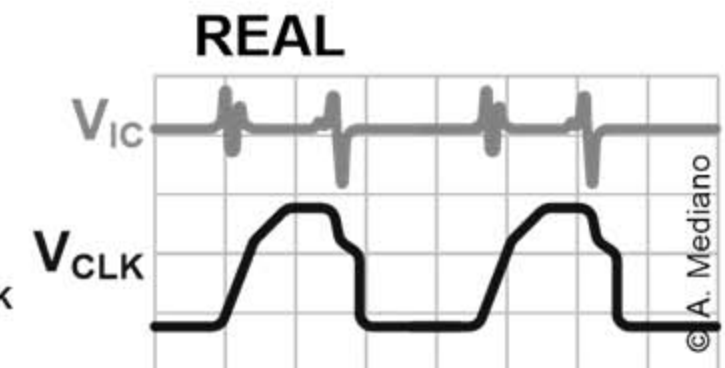
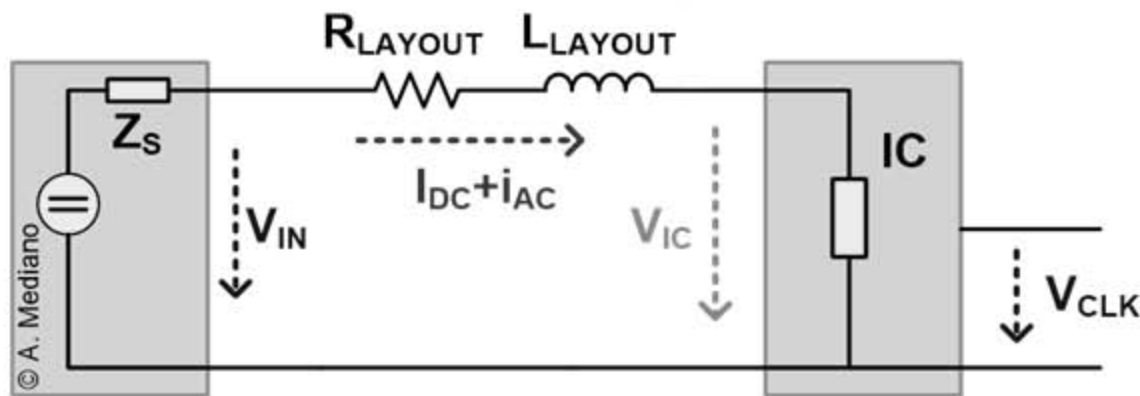
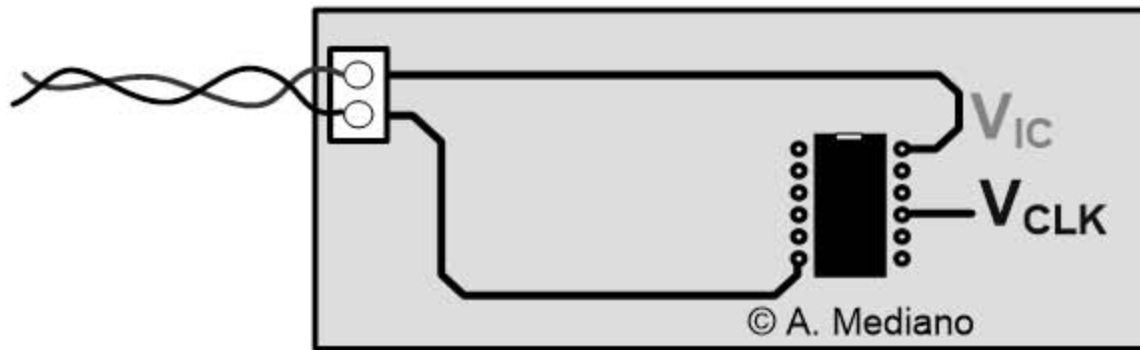
SI: Eye diagram



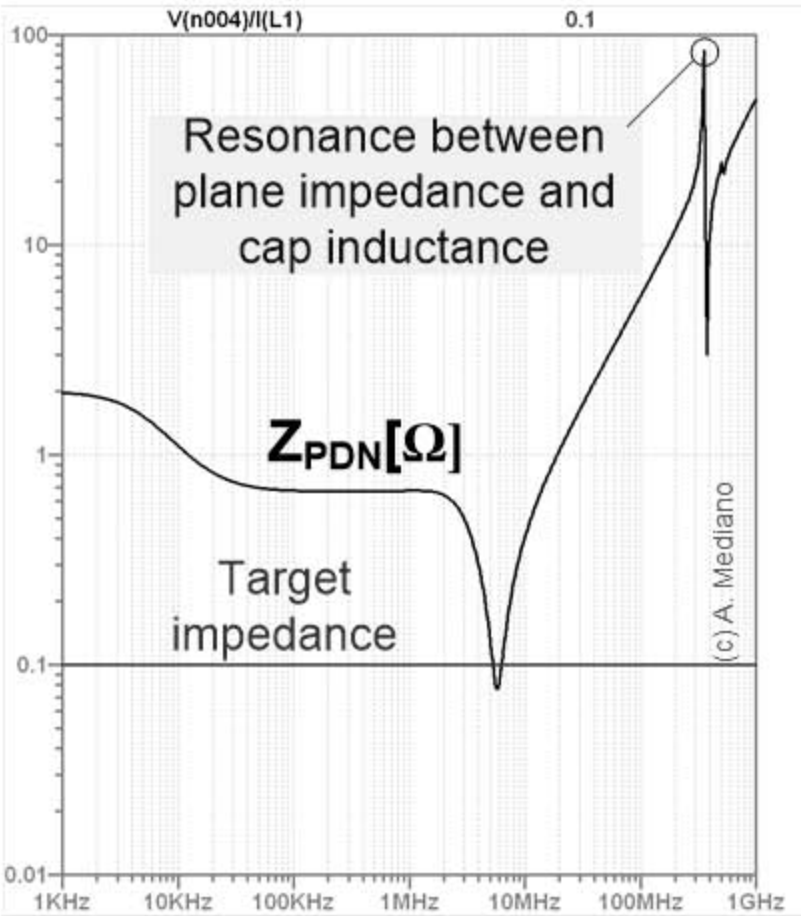
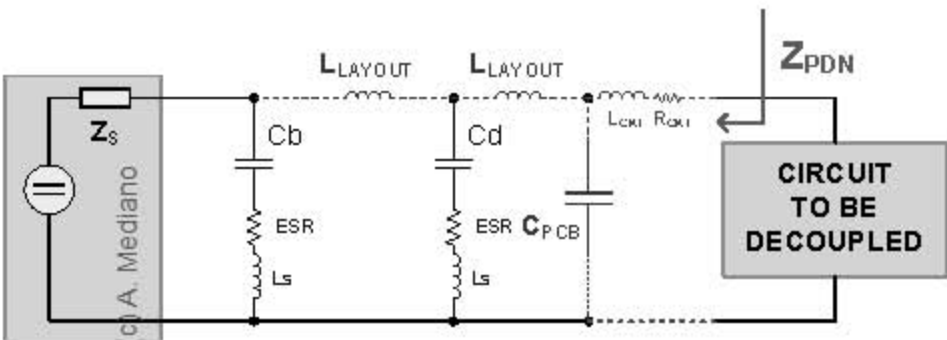
PCBs: TX lines and matching



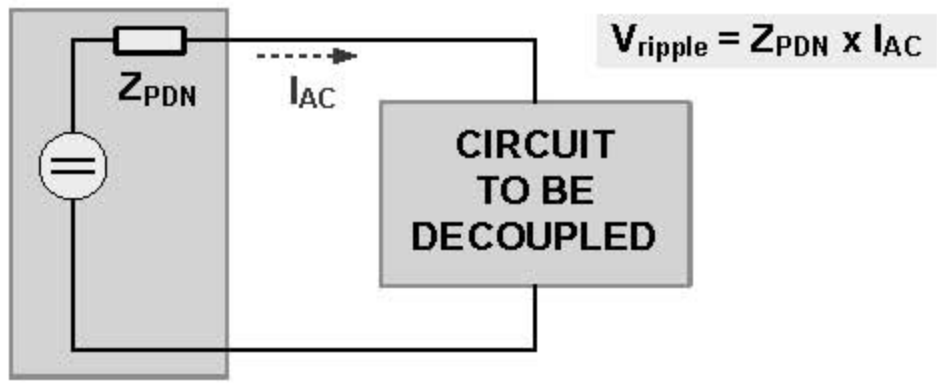
PCBs: Decoupling



PCBs: PDN



EQUIVALENT CIRCUIT



Rohde & Schwarz: RTO/RTE scopes

- **Time domain** and **frequency domain** in one instrument (synchronized!!).
- **Big record length** ensuring that you capture enough information.
- **Sample rate** $> 2 \times f_{MAX}$ (e.g. 2.5 GS/s in DC to 1GHz)
- Inputs: "High" impedance and **50 Ω** .
- Vertical scale: good sensitivity (i.e. dynamic range) **1 - 5mV/DIV**
- **Powerful frequency analysis:**
 - Advanced FFT \neq Traditional FFT
 - Spectrum analyzer "style": CENTER FREQ, SPAN and RBW.
 - FFT analysis not time domain setup configuration dependence.
 - FFT with ZOOM.
 - FFT with GATING technique: easy to identify spurious EMI in time domain.
- **Display:**
 - i) color table; ii) powerful persistence mode to detect CW signals vs burst
- **Masks** with configurable actions !!!!



Rohde & Schwarz: ZNL network analyzers

- **Frequency range:**
 - 5 kHz to 3 GHz: R&S®ZNL3
 - 5 kHz to 6 GHz: R&S®ZNL6
- **Two-port vector network analyzer** for bidirectional measurements
- **Wide dynamic range** of typ. 130 dB
- **Output power** range from **-40dBm to +3dBm**
- **Measurement bandwidths** from 1Hz-500kHz
- **Fast measurements**
- **Compact size and low weight** (6 kg to 8 kg)
- **Optional battery pack available**

